

# **SOT-23 Plastic-Encapsulate Transistors**

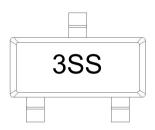
### **Features**

- · Low profile package
- Ldeal forautomated placement
- Power Dissipation of 200mW
- High Stability and High Reliability
- RoHS compliant





SOT-23

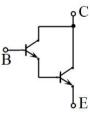




Package: SOT-23

- 1: Base
- 2: Emitter
- 3: Collector

#### Epuivalent circuit



### **Applications**

- Amplifying signal
- Electronic switch
- Oscillating circui
- Variable resistance

### **Mechanical Data**

- Package: SOT-23
- Lead finish:matte tin
- Case material: " green " molding compound.
- UL flammability classification rating 94V -0
- Moisture sensitivity: level 1 per J -STD-020



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Absolute Maximum Ratings (T <sub>A</sub> =25°C unless otherwise noted)			
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V
Emitter-Base Voltage	V <sub>EBO</sub>	12	V
Collector Current - Continuous	Ι <sub>C</sub>	500	mA
Collector Power Dissipation	Pc	200	mW
ThermalResistance From Junction to Ambient	$R_{ extsf{ heta}JA}$	625	°C/W
Junction Temperature	TJ	-55 to +150	°C
Junction and Storage Temperature	Т <sub>stg</sub>	-55 to +150	°C

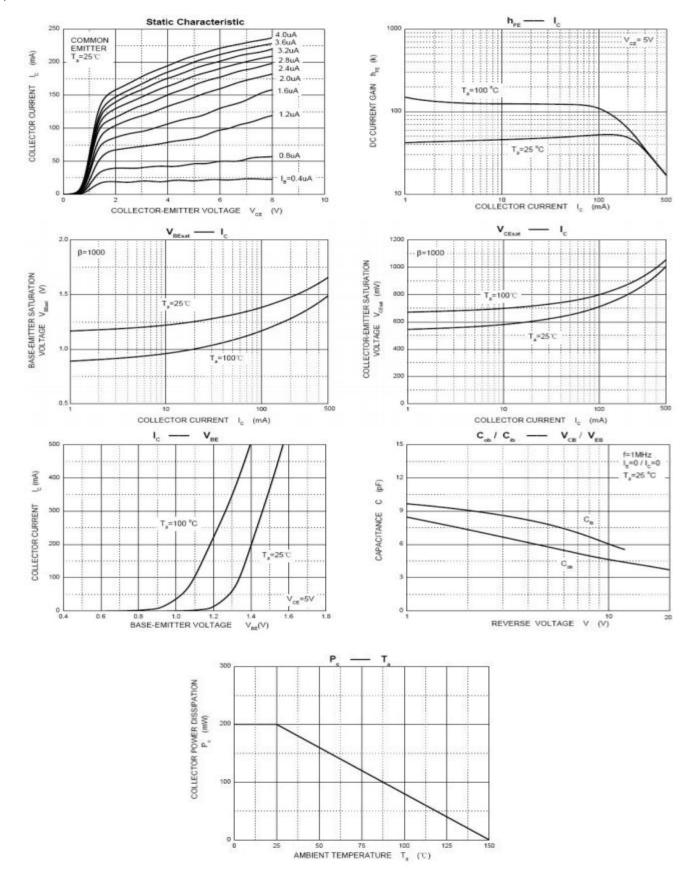
Electrical Characteristics (T <sub>A</sub> = 25 °C unless otherwise noted)					
Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100uA, I <sub>E</sub> =0	80		V
Collector-emitter breakdown voltage	V <sub>(BR)CES</sub>	I <sub>C</sub> =100uA, V <sub>BE</sub> =0	80		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10uA, I <sub>C</sub> =0	12		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =60V, I <sub>E</sub> =0		100	nA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =60V, I <sub>B</sub> =0		500	nA
Emitter cut-off current	I <sub>EB O</sub>	V <sub>EB</sub> =10V, I <sub>C</sub> =0		100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	10K		
		I <sub>C</sub> =10mA, I <sub>B</sub> =0.01mA		1.2	V
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =0.1mA		1.5	V
Base -emitter saturation voltage	V <sub>BE(ON)</sub>	V <sub>CE</sub> =5V,I <sub>C</sub> =100mA		2	V
Transition frequency	f⊤	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA,f=100MHz	125		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =1V, I <sub>E</sub> =0, f=1MHz		8	pF



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# **Ratings and Characteristics Curves**

#### $(TA = 25^{\circ}C \text{ unless otherwise note})$

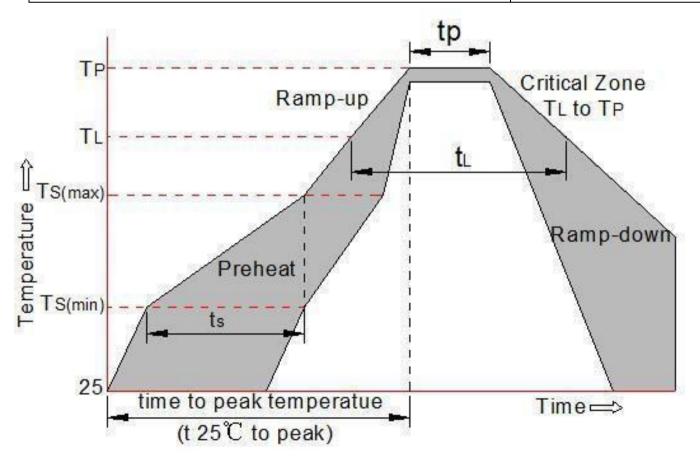




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### Soldering parameters

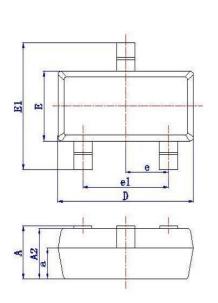
Reflow Condition		Pb -Free assembly (see as bellow)
	-Temperature Min (T <sub>s(min)</sub> )	+150 ℃
Pre Heat	-Temperature Max(T <sub>s(max)</sub> )	+200 °C
	-Time (Min to Max) (ts)	60 -180 secs.
Average	ramp up rate (Liquid us Temp (T L) to peak)	3 ℃ /sec. Max
	Ts(maxt)o T L- Ramp -up Rate	3 ℃ /sec. Max
	-Temperature(T L) (Liquid us)	+217 ℃
Reflow	-Temperature(t L)	60 -150 secs.
	Peak Temp (T p)	+260(+0/ -5) ℃
Time within 5 $\degree$ C of actual Peak Temp (tp)		30 secs. Max
Ramp -down Rate		6 ℃ /sec. Max
	Time 25 °C to Peak Temp (T P)	8 min. Max
Do not exceed		<b>+260</b> ℃

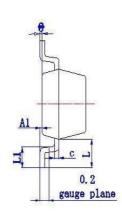




# Package Outline Dimensions

millimeters





	Dimensional		
Symbol	Millimeters		
	min	max	
А	0.9	1.15	
A1	0	0.1	
A2	0.9	1.05	
а	(0.6)		
D	2.8	3.0	
E	1.2	1.4	
E1	2.25	2.55	
е	(0.95)		
e1	1.8	2.0	
b	0.3	0.5	
С	0.08	0.15	
L	(0.55)		
L1	0.3	0.5	
θ	0°	8°	

## **Revision History**

Document Version	Date of release	Description of changes	
Rev.A	2020.01.26	First issue	



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